Single Buffer/Line Driver; 3-state

CJ74LVC1G125 Logic

1 Introduction

The CJ74LVC1G125 provides one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (/OE). A HIGH-level at pin /OE causes the output to assume a high-impedance OFF-state.

The input can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment.

2 Available Packages

PART NUMBER	PACKAGE
CJ74LVC1G125	SOT-23-5L
	SOT-353
	DFN1x1-6L

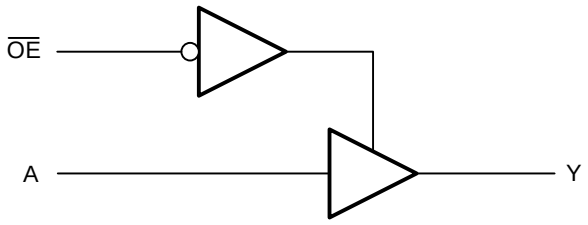
Note: For all available packages, please refer to the part Orderable Information.

3 Features

- Supply voltage range:1.65V to 5.5V
- ±24mA output drive (V_{CC}=3.0V)
- CMOS low power consumption
- Temperature range: -40°C to +125°C

4 Applications

- Cable Modem Termination System
- High-Speed Data Acquisition and Generation
- Military: Radar and Sonar
- Motor Control: High-Voltage
- Power Line Communication Modem
- SSD: Internal or External
- Video Broadcasting and Infrastructure: Scalable Platform
- Video Broadcasting: IP-Based Multi-Format Transcoder
- Video Communications System



Simplified diagram

5 Orderable Information

DEVICE	PACKAGE	OP TEMP	ECO PLAN	MSL	PACKING OPTION	SORT
CJ74LVC1G125M5N	SOT-23-5L	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 3000 Units / Reel	Active
CJ74LVC1G125R5N	SOT-353	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 3000 Units / Reel	Active
CJ74LVC1G125DKN	DFN1x1-6L	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 5000 Units / Reel	Active

Note:

ECO PLAN: For the RoHS and Green certification standards of this product, please refer to the official report provided by JSCJ.

MSL: Moisture Sensitivity Level. Determined according to JEDEC industry standard classification.

SORT: Specifically defined as follows:
Active: Recommended for new products;
Customized: Products manufactured to meet the specific needs of customers;
Preview: The device has been released and has not been fully mass produced. The sample may or may not be available;
NoRD: It is not recommended to use the device for new design. The device is only produced for the needs of existing customers;
Obsolete: The device has been discontinued.

6 Pin Configuration and Marking Information

6.1 Pin Configuration

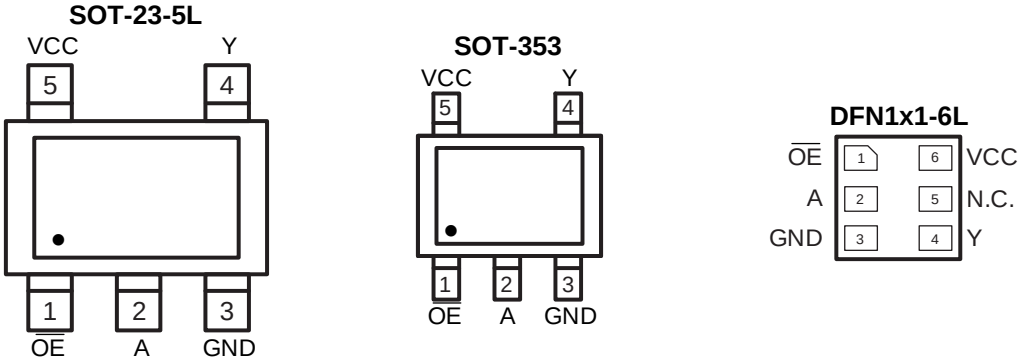


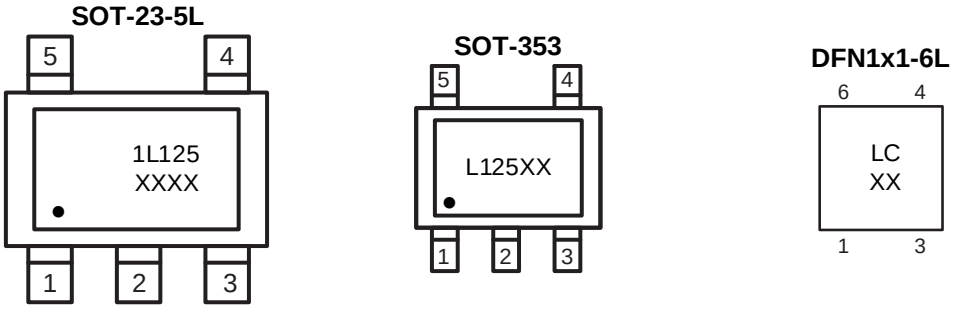
Figure 6-1 Pin configuration

6.2 Pin Function

PIN		NAME	I/O(1)	DESCRIPTION
No.				
SOT-23-5L/SOT-353	DFN1x1-6L			
1	1	$\overline{OE}$	I	Output enable input
2	2	A	I	Data input
3	3	GND	G	Ground (0V)
4	4	Y	O	Data output
-	5	N.C.	-	Not connected
5	6	VCC	P	Supply voltage

(1) I-Input, O-Output, P-Power, G-Ground

6.3 Marking Information



XXXX or XX: Code, indicates weekly record information.

7 Specifications

7.1 Absolute Maximum Ratings

Voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	Supply voltage	-	-0.5	+6.5	V
I_{IK}	Input clamping current	V_I < 0V	-50	-	mA
V_I	Input voltage	-	-0.5	+6.5	V
I_{OK}	Output clamping current	V_O > V_{CC} or V_O < 0V	-	±50	mA
V_O	Output voltage	Active mode	-0.5	V_{CC}+0.5	V
		Power-down mode	-0.5	+6.5	V
I_O	Output current	V_O=0V to V_{CC}	-	±50	mA
I_{CC}	Supply current	-	-	100	mA
I_{GND}	Ground current	-	-100	-	mA
T_{stg}	Storage temperature	-	-65	+150	°C
T_L	Soldering temperature	10s	-	260	°C

Note: Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to GND. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

7.2 Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CC}	Supply voltage	-	1.65	-	5.5	V
V_I	Input voltage	-	0	-	5.5	V
V_O	Output voltage	Active mode	0	-	V_{CC}	V
		Power-down mode; V_{CC}=0V	0	-	5.5	V
T_{amb}	Ambient temperature	-	-40	-	+125	°C

7.3 ESD Ratings

SYMBOL	ESD RATINGS		VALUE	UNIT
$V_{ESD-HBM}$	Electrostatic discharge	Human body model (HBM)(1)	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.4 Electrical Characteristics

7.4.1 DC Characteristics 1

T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
V_{IH}	HIGH-level input voltage	V_{CC}=1.65V to 1.95V		0.65xV_{CC}	-	-	V
		V_{CC}=2.3V to 2.7V		1.7	-	-	V
		V_{CC}=2.7V to 3.6V		2.0	-	-	V
		V_{CC}=4.5V to 5.5V		0.7xV_{CC}	-	-	V
V_{IL}	LOW-level input voltage	V_{CC}=1.65V to 1.95V		-	-	0.35xV_{CC}	V
		V_{CC}=2.3V to 2.7V		-	-	0.7	V
		V_{CC}=2.7V to 3.6V		-	-	0.8	V
		V_{CC}=4.5V to 5.5V		-	-	0.3xV_{CC}	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}	I_O=-100uA; V_{CC}=1.65V to 5.5V	V_{CC} - 0.1	-	-	V
			I_O=-4mA; V_{CC}=1.65V	1.2	-	-	V
			I_O=-8mA; V_{CC}=2.3V	1.9	-	-	V
			I_O=-12mA; V_{CC}=2.7V	2.2	-	-	V
			I_O=-24mA; V_{CC}=3.0V	2.3	-	-	V
			I_O=-32mA; V_{CC}=4.5V	3.8	-	-	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}	I_O=100uA; V_{CC}=1.65V to 5.5V	-	-	0.10	V
			I_O=4mA; V_{CC}=1.65V	-	-	0.45	V
			I_O=8mA; V_{CC}=2.3V	-	-	0.30	V
			I_O=12mA; V_{CC}=2.7V	-	-	0.40	V
			I_O=24mA; V_{CC}=3.0V	-	-	0.55	V
			I_O=32mA; V_{CC}=4.5V	-	-	0.55	V
I_I	Input leakage current	V_I=5.5V or GND; V_{CC}=0V to 5.5V		-	-	±2	uA
I_{OZ}	OFF-state output current	V_I=V_{IH} or V_{IL}; V_O=5.5V or GND; V_{CC}=3.6V		-	-	±2	uA
I_{OFF}	Power-off leakage current	V_I or V_O=5.5V; V_{CC}=0V		-	-	±2	uA
I_{CC}	Supply current	V_I=5.5V or GND; I_O=0A; V_{CC}=1.65V to 5.5V		-	-	2	uA
ΔI_{CC}	Additional supply current	Per pin; V_I=V_{CC}-0.6V; I_O=0A; V_{CC}=2.3V to 5.5V		-	-	500	uA

(1) All typical values are measured at V_{CC}=3.3V and T_{amb}=25°C.

7.4.2 DC Characteristics 2

T_{amb}=-40°C to +125°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
V_{IH}	HIGH-level input voltage	V_{CC}=1.65V to 1.95V		0.65xV_{CC}	-	-	V
		V_{CC}=2.3V to 2.7V		1.7	-	-	V
		V_{CC}=2.7V to 3.6V		2.0	-	-	V
		V_{CC}=4.5V to 5.5V		0.7xV_{CC}	-	-	V
V_{IL}	LOW-level input voltage	V_{CC}=1.65V to 1.95V		-	-	0.35xV_{CC}	V
		V_{CC}=2.3V to 2.7V		-	-	0.7	V
		V_{CC}=2.7V to 3.6V		-	-	0.8	V
		V_{CC}=4.5V to 5.5V		-	-	0.3xV_{CC}	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}	I_O=-100uA; V_{CC}=1.65V to 5.5V	V_{CC} - 0.1	-	-	V
			I_O=-4mA; V_{CC}=1.65V	0.95	-	-	V
			I_O=-8mA; V_{CC}=2.3V	1.7	-	-	V
			I_O=-12mA; V_{CC}=2.7V	1.9	-	-	V
			I_O=-24mA; V_{CC}=3.0V	2.0	-	-	V
			I_O=-32mA; V_{CC}=4.5V	3.4	-	-	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}	I_O=100uA; V_{CC}=1.65V to 5.5V	-	-	0.10	V
			I_O=4mA; V_{CC}=1.65V	-	-	0.70	V
			I_O=8mA; V_{CC}=2.3V	-	-	0.45	V
			I_O=12mA; V_{CC}=2.7V	-	-	0.60	V
			I_O=24mA; V_{CC}=3.0V	-	-	0.80	V
			I_O=32mA; V_{CC}=4.5V	-	-	0.80	V
I_I	Input leakage current	V_I=5.5V or GND; V_{CC}=0V to 5.5V		-	-	±4	uA
I_{OZ}	OFF-state output current	V_I=V_{IH} or V_{IL}; V_O=5.5V or GND; V_{CC}=3.6V		-	-	±4	uA
I_{OFF}	Power-off leakage current	V_I or V_O=5.5V; V_{CC}=0V		-	-	±4	uA
I_{CC}	Supply current	V_I=5.5V or GND; I_O=0A; V_{CC}=1.65V to 5.5V		-	-	4	uA
ΔI_{CC}	Additional supply current	Per pin; V_I=V_{CC}-0.6V; I_O=0A; V_{CC}=2.3V to 5.5V		-	-	500	uA

(1) All typical values are measured at V_{CC}=3.3V and T_{amb}=25°C.

7.4.3 AC Characteristics 1

T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.(1)	MAX.	UNIT
t_{PLH}, t_{PHL}	A to Y propagation delay	See Figure 8-3	V_{CC}=1.65V to 1.95V	-	9.9	14.9	ns
			V_{CC}=2.3V to 2.7V	-	6.6	9.9	ns
			V_{CC}=2.7V	-	7.5	11.3	ns
			V_{CC}=3.0V to 3.6V	-	6.3	9.5	ns
			V_{CC}=4.5V to 5.5V	-	5.1	7.7	ns
t_{PZH}, t_{PZL}	$\overline{OE}$ to Y enable time	See Figure 8-4	V_{CC}=1.65V to 1.95V	-	12.3	18.5	ns
			V_{CC}=2.3V to 2.7V	-	8.4	12.6	ns
			V_{CC}=2.7V	-	9.9	14.9	ns
			V_{CC}=3.0V to 3.6V	-	7.2	10.8	ns
			V_{CC}=4.5V to 5.5V	-	6.3	9.5	ns
t_{PLZ}, t_{PHZ}	$\overline{OE}$ to Y disable time	See Figure 8-4	V_{CC}=1.65V to 1.95V	-	12.9	19.4	ns
			V_{CC}=2.3V to 2.7V	-	8.1	12.2	ns
			V_{CC}=2.7V	-	9.0	13.5	ns
			V_{CC}=3.0V to 3.6V	-	9.3	14.0	ns
			V_{CC}=4.5V to 5.5V	-	6.6	9.9	ns

(1) Typical values are measured at T_{amb}=25°C and V_{CC}=1.8V, 2.5V, 2.7V, 3.3V and 5.0V respectively.

7.4.4 AC Characteristics 2

T_{amb}=-40°C to +125°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
t_{PLH}, t_{PHL}	A to Y propagation delay	See Figure 8-3	V_{CC}=1.65V to 1.95V	-	-	19.5	ns
			V_{CC}=2.3V to 2.7V	-	-	12.6	ns
			V_{CC}=2.7V	-	-	14.3	ns
			V_{CC}=3.0V to 3.6V	-	-	12.6	ns
			V_{CC}=4.5V to 5.5V	-	-	10.5	ns
t_{PZH}, t_{PZL}	$\overline{OE}$ to Y enable time	See Figure 8-4	V_{CC}=1.65V to 1.95V	-	-	23.6	ns
			V_{CC}=2.3V to 2.7V	-	-	16.2	ns
			V_{CC}=2.7V	-	-	19.1	ns
			V_{CC}=3.0V to 3.6V	-	-	14.3	ns
			V_{CC}=4.5V to 5.5V	-	-	12.3	ns
t_{PLZ}, t_{PHZ}	$\overline{OE}$ to Y disable time	See Figure 8-4	V_{CC}=1.65V to 1.95V	-	-	25.2	ns
			V_{CC}=2.3V to 2.7V	-	-	15.8	ns
			V_{CC}=2.7V	-	-	17.6	ns
			V_{CC}=3.0V to 3.6V	-	-	18.1	ns
			V_{CC}=4.5V to 5.5V	-	-	13.0	ns

8 Detailed Description

8.1 Overview

The CJ74LVC1G125 provides one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (/OE). A HIGH-level at pin /OE causes the output to assume a high-impedance OFF-state.

The input can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment.

8.2 Functional Block Diagram

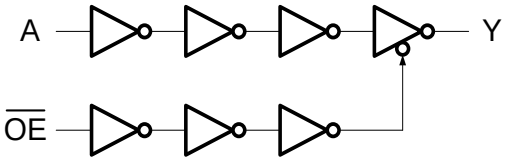


Figure 8-1 Logic diagram

8.3 Function Table(1)

INPUT		OUTPUT
$\overline{OE}$	A	Y
L	L	L
L	H	H
H	X	Z

(1) H=HIGH voltage level; L=LOW voltage level; X=don't care; Z=high-impedance OFF-state.

8.4 Testing Circuit

8.4.1 AC Testing Circuit

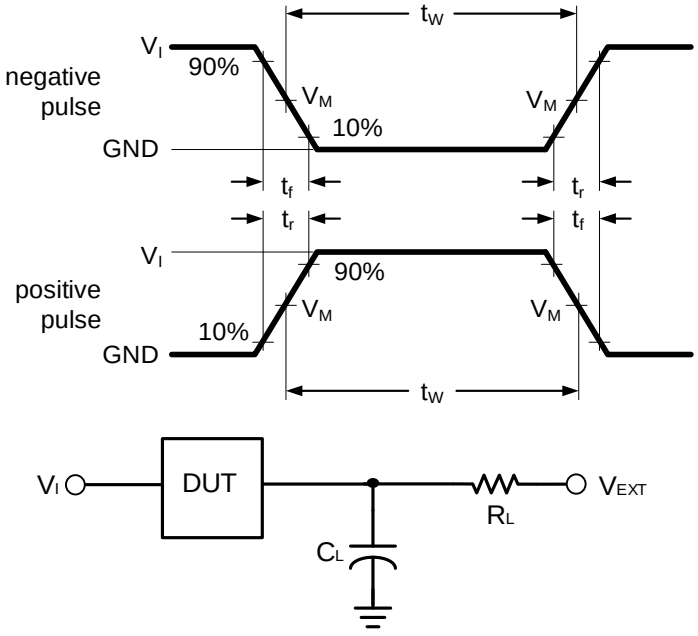


Figure 8-2 Load circuit

Definitions for test circuit:

C_L includes probe and jig capacitance.

8.4.2 AC Testing Waveforms

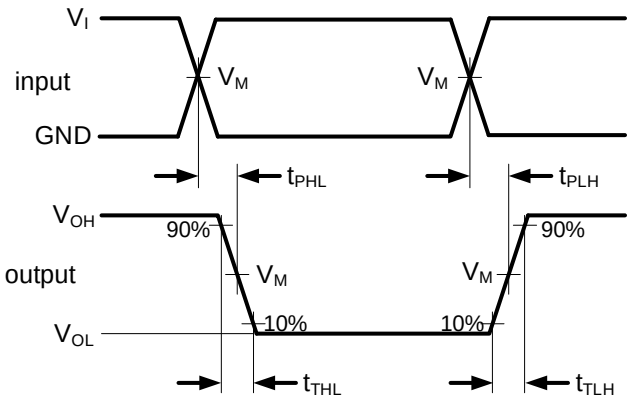


Figure 8-3 The input A to output Y propagation delay times

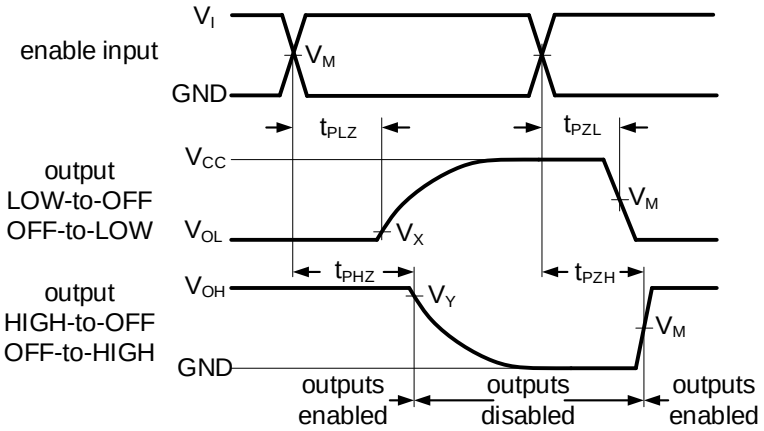


Figure 8-4 3-state enable and disable times

8.4.3 Measurement Points

SUPPLY VOLTAGE	INPUT	OUTPUT		
V_{CC}	V_M	V_M	V_X	V_Y
1.65V to 1.95V	0.5xV_{CC}	0.5xV_{CC}	V_{OL}+0.15V	V_{OH}-0.15V
2.3V to 2.7V	0.5xV_{CC}	0.5xV_{CC}	V_{OL}+0.15V	V_{OH}-0.15V
2.7V	1.5V	1.5V	V_{OL}+0.3V	V_{OH}-0.3V
3.0V to 3.6V	1.5V	1.5V	V_{OL}+0.3V	V_{OH}-0.3V
4.5V to 5.5V	0.5xV_{CC}	0.5xV_{CC}	V_{OL}+0.3V	V_{OH}-0.3V

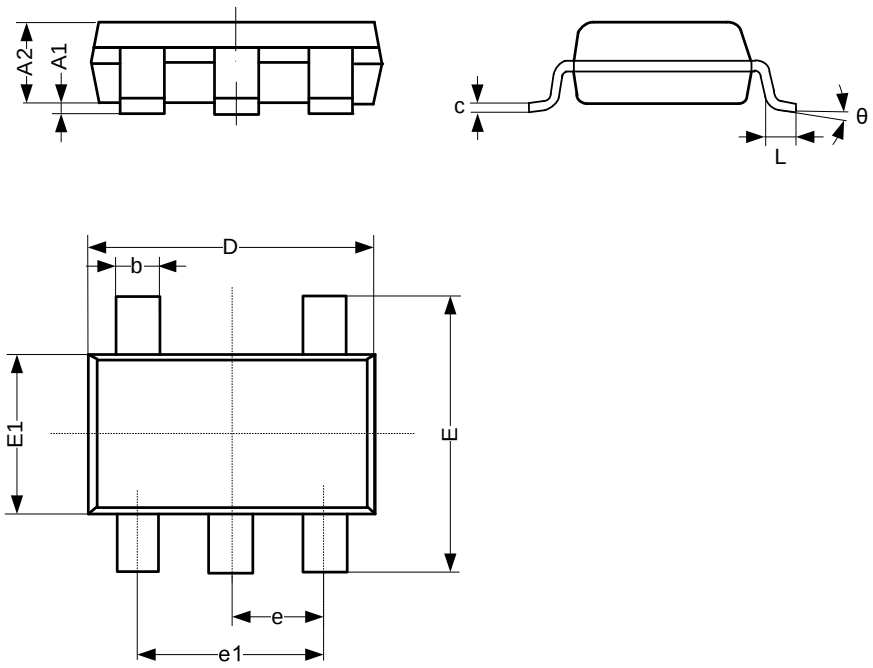
8.4.4 Test Data

SUPPLY VOLTAGE	INPUT		LOAD		V_{EXT}		
V_{CC}	V_I	t_r, t_f	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
1.65V to 1.95V	V_{CC}	≤ 3ns	30pF	1kΩ	Open	GND	2xV_{CC}
2.3V to 2.7V	V_{CC}	≤ 3ns	30pF	500Ω	Open	GND	2xV_{CC}
2.7V	2.7V	≤ 3ns	50pF	500Ω	Open	GND	6V
3.0V to 3.6V	2.7V	≤ 3ns	50pF	500Ω	Open	GND	6V
4.5V to 5.5V	V_{CC}	≤ 3ns	50pF	500Ω	Open	GND	2xV_{CC}

9 Mechanical Information

9.1 SOT-23-5L Mechanical Information

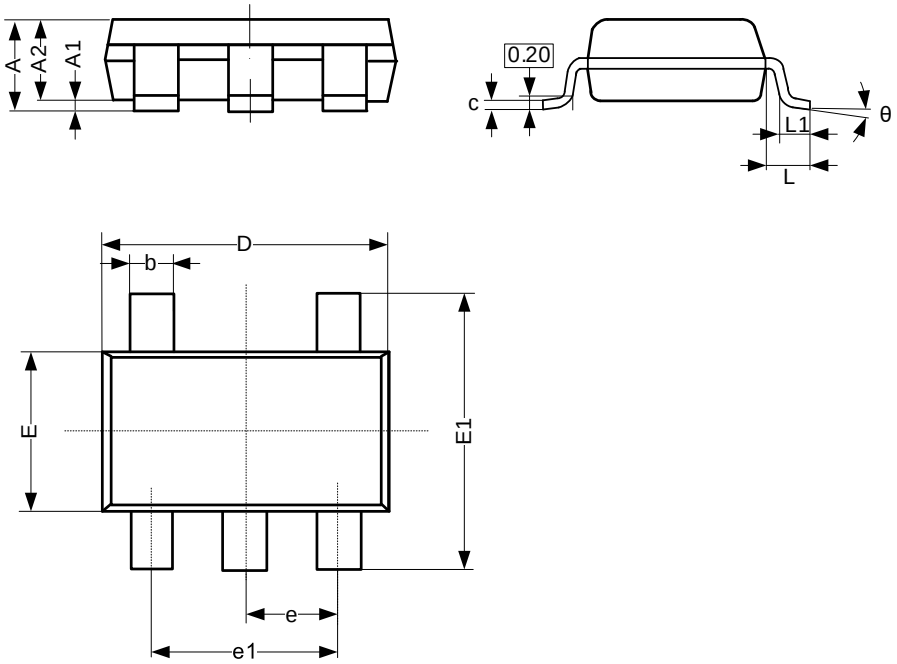
9.1.1 SOT-23-5L Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A1	0.00	-	0.12
A2	1.00	-	1.20
b	0.30	-	0.50
c	0.10	-	0.20
D	2.82	-	3.02
E	2.60	-	3.00
E1	1.50	-	1.70
e	0.95 BSC		
e1	1.80	-	2.00
L	0.30	-	0.60
Θ	0°	-	8°
Unit: mm			

9.2 SOT-353 Mechanical Information

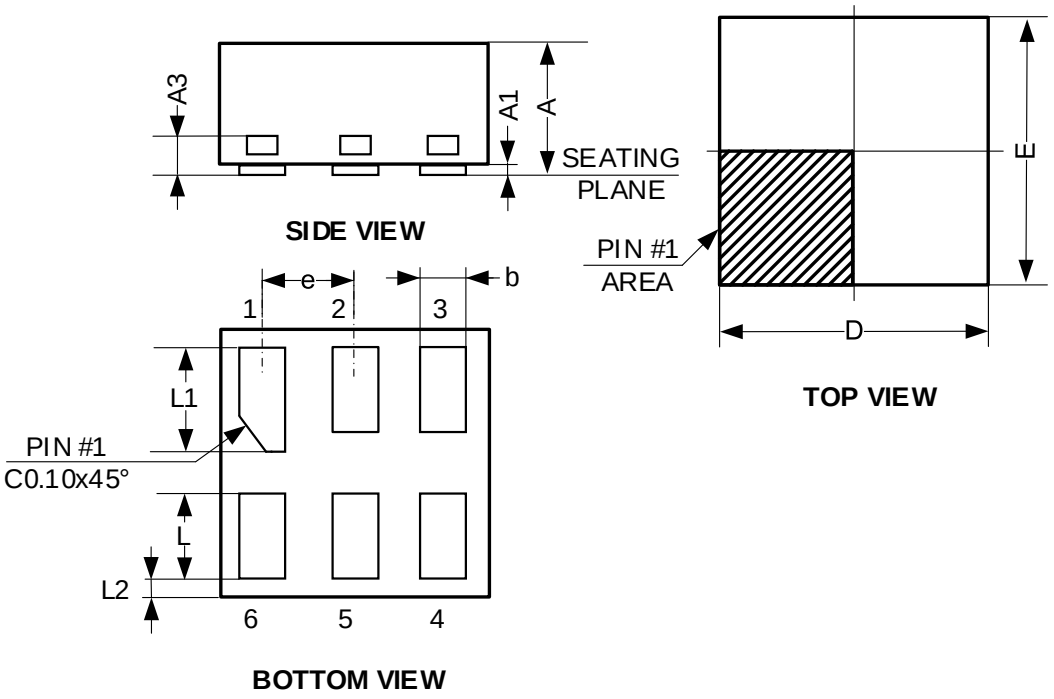
9.2.1 SOT-353 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.90	-	1.10
A1	0.00	-	0.10
A2	0.90	-	1.00
b	0.15	-	0.35
c	0.11	-	0.175
D	2.00	-	2.20
E	1.15	-	1.35
E1	2.15	-	2.45
e	0.65 BSC		
e1	1.20	-	1.40
L	-	0.525	-
L1	0.26	-	0.46
Θ	0°	-	8°
Unit: mm			

9.3 DFN1x1-6L Mechanical Information

9.3.1 DFN1x1-6L Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.41	-	0.50
A1	0.00	-	0.05
A3	-	0.127	-
b	0.11	-	0.21
D	-	1.00	-
E	-	1.00	-
e	0.35 BSC		
L	0.26	-	0.36
L1	0.31	-	0.41
L2	0.02	-	0.12
Unit: mm			

10 Notes and Revision History

10.1 Associated Product Family and Others

To view other products of the same type or IC products of other types, click the official website of JSCJ -- ***https:www.jscj-elec.com*** for more details.

10.2 Notes

Electrostatic Discharge Caution

This IC may be damaged by ESD. Relevant personnel shall comply with correct installation and use specifications to avoid ESD damage to the IC. If appropriate measures are not taken to prevent ESD damage, the hazards caused by ESD include but are not limited to degradation of integrated circuit performance or complete damage of integrated circuit. For some precision integrated circuits, a very small parameter change may cause the whole device to be inconsistent with its published specifications.

10.3 Revision History

June, 2025: rev - 1.2, Change SOT353 marking information.

July, 2025: rev - 1.4, Change marking information.

December, 2025: rev - 1.5, Change DFN1x1-6L marking information.

DISCLAIMER

IMPORTANT NOTICE, PLEASE READ CAREFULLY

The information in this data sheet is intended to describe the operation and characteristics of our products. JSCJ has the right to make any modification, enhancement, improvement, correction or other changes to any content in this data sheet, including but not limited to specification parameters, circuit design and application information, without prior notice.

Any person who purchases or uses JSCJ products for design shall: 1. Select products suitable for circuit application and design; 2. Design, verify and test the rationality of circuit design; 3. Procedures to ensure that the design complies with relevant laws and regulations and the requirements of such laws and regulations. JSCJ makes no warranty or representation as to the accuracy or completeness of the information contained in this data sheet and assumes no responsibility for the application or use of any of the products described in this data sheet.

Without the written consent of JSCJ, this product shall not be used in occasions requiring high quality or high reliability, including but not limited to the following occasions: medical equipment, military facilities and aerospace. JSCJ shall not be responsible for casualties or property losses caused by abnormal use or application of this product.

Official Website: www.jscj-elec.com